CEL

NPN SILICON RF TRANSISTOR

NE66219 / 2SC5606

JEITA Part No.

NPN SILICON RF TRANSISTOR FOR LOW NOISE · HIGH-GAIN AMPLIFICATION 3-PIN ULTRA SUPER MINIMOLD (19, 1608 PKG)

FEATURES

- Suitable for high-frequency oscillation
- f_T = 25 GHz technology adopted
- 3-pin ultra super minimold (19, 1608 PKG) package

<R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NE66219 2SC5606	NE66219-A 2SC5606-A	3-pin ultra super minimold (19, 1608 PKG) (Pb-Free)	50 pcs (Non reel)	• 8 mm wide embossed taping • Pin 3 (collector) face the perforation side of the tape
NE66219-T1 2SC5606-T1	NE66219-T1-A 2SC5606-T1-A		3 kpcs/reel	

Remark To order evaluation samples, please contact your nearby sales office.
The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	15	V
Collector to Emitter Voltage	V_{CEO}	3.3	V
Emitter to Base Voltage	V_{EBO}	1.5	V
Collector Current	I_C	35	mA
Total Power Dissipation	P_{tot} Note	115	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	−65 to +150	°C

Note Mounted on 1.08 $cm^2 \times 1.0$ mm (t) glass epoxy substrate

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

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Date Published August 2009 NS

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I_{CBO}	V_{CB} = 5 V, I_E = 0 mA	–	–	200	nA
Emitter Cut-off Current	I_{EBO}	V_{EB} = 1 V, I_C = 0 mA	–	–	200	nA
DC Current Gain	h_{FE} Note 1	V_{CE} = 2 V, I_C = 5 mA	60	80	100	–
RF Characteristics						
Gain Bandwidth Product	f_T	V_{CE} = 2 V, I_C = 20 mA, f = 2 GHz	–	21	–	GHz
Insertion Power Gain	$\|S_{21e}\|^2$	V_{CE} = 2 V, I_C = 20 mA, f = 2 GHz	10	12.5	–	dB
Noise Figure	NF	V_{CE} = 2 V, I_C = 5 mA, f = 2 GHz, $Z_S = Z_{opt}$	–	1.2	1.5	dB
Reverse Transfer Capacitance	C_{re} Note 2	V_{CB} = 2 V, I_E = 0 mA, f = 1 MHz	–	0.21	0.3	pF
Maximum Available Power Gain	MAG Note 3	V_{CE} = 2 V, I_C = 20 mA, f = 2 GHz	–	14	–	dB
Maximum Stable Power Gain	MSG Note 4	V_{CE} = 2 V, I_C = 20 mA, f = 2 GHz	–	15	–	dB

Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

2. Collector to base capacitance when the emitter grounded

3. $MAG = \left|\frac{S_{21}}{S_{12}}\right| (K - \sqrt{(K^2 - 1)})$

4. $MSG = \left|\frac{S_{21}}{S_{12}}\right|$

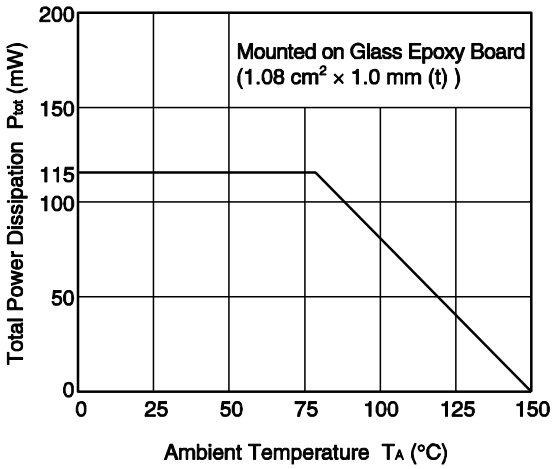
h_{FE} CLASSIFICATION

<R>

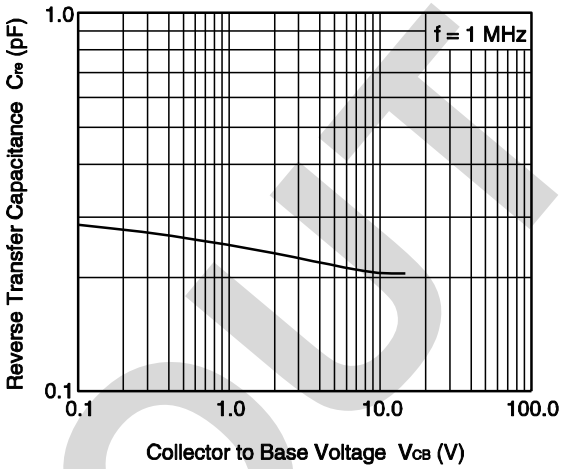
Rank	FB/YFB
Marking	UA
h_{FE}	60 to 100

<R> **TYPICAL CHARACTERISTICS (Unless otherwise specified, T_A = +25°C)**

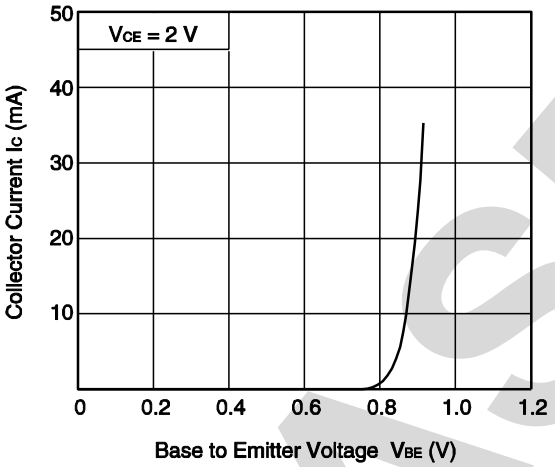
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



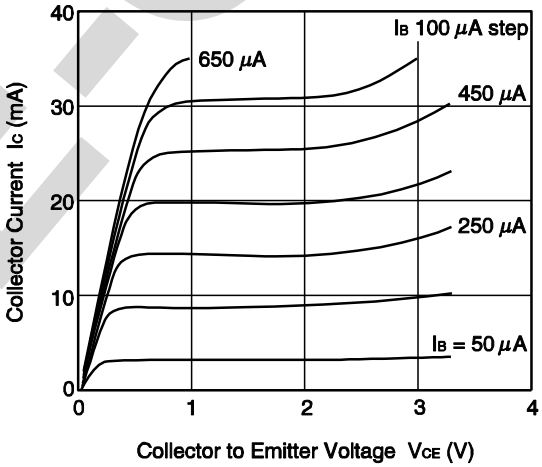
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



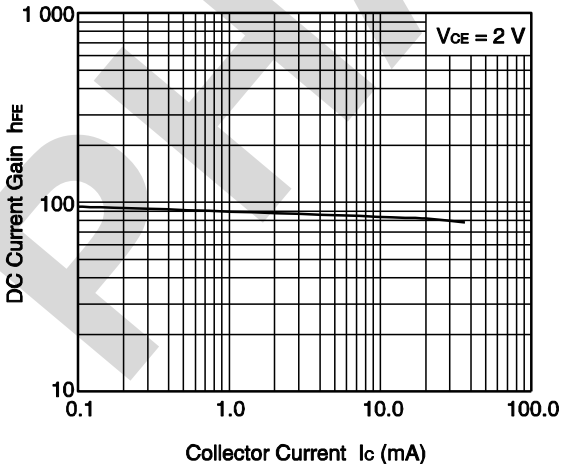
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

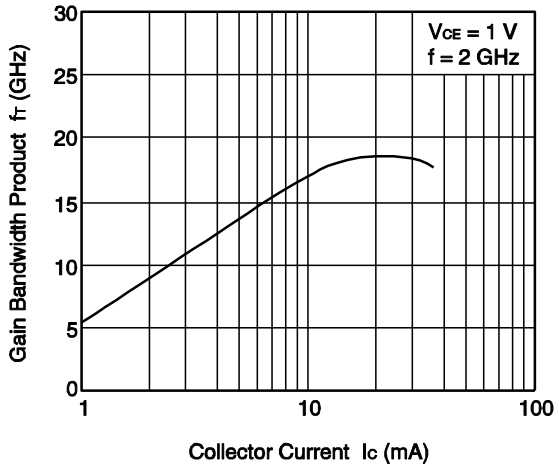


DC CURRENT GAIN vs. COLLECTOR CURRENT

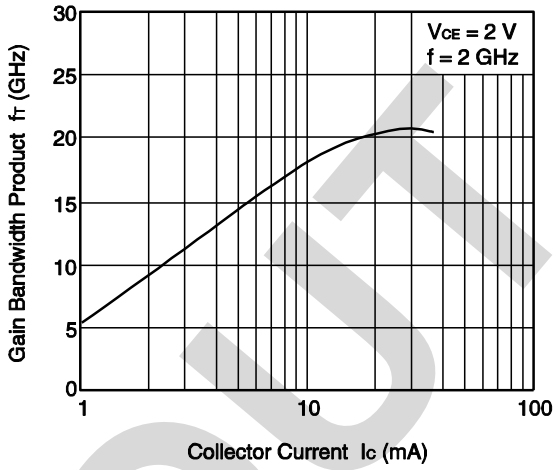


Remark The graphs indicate nominal characteristics.

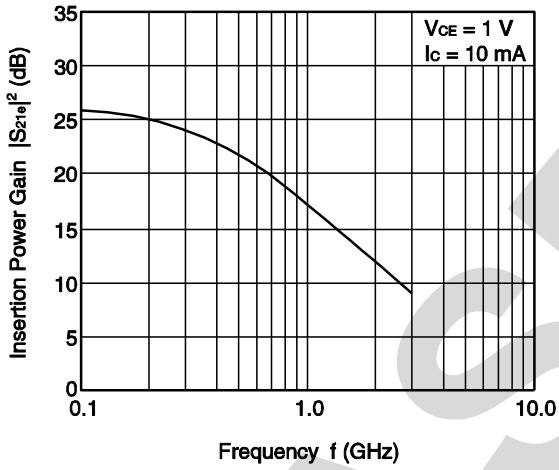
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



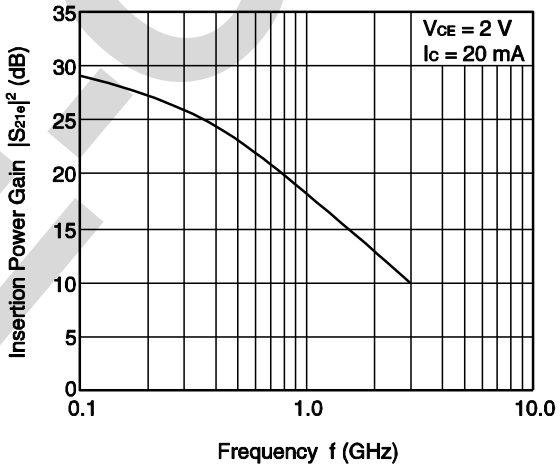
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



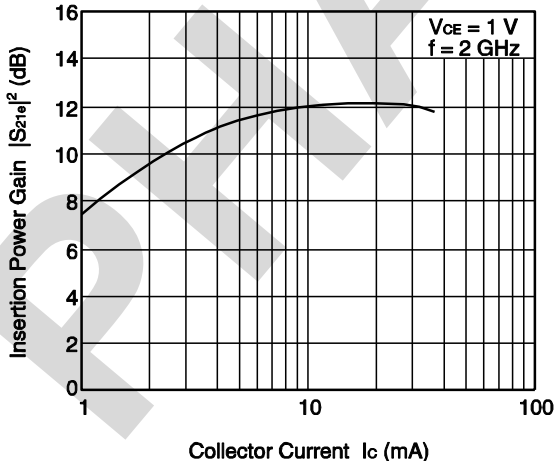
INSERTION POWER GAIN vs. FREQUENCY



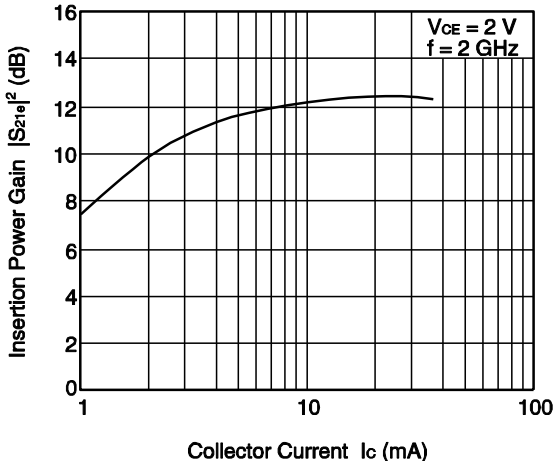
INSERTION POWER GAIN vs. FREQUENCY



INSERTION POWER GAIN vs. COLLECTOR CURRENT

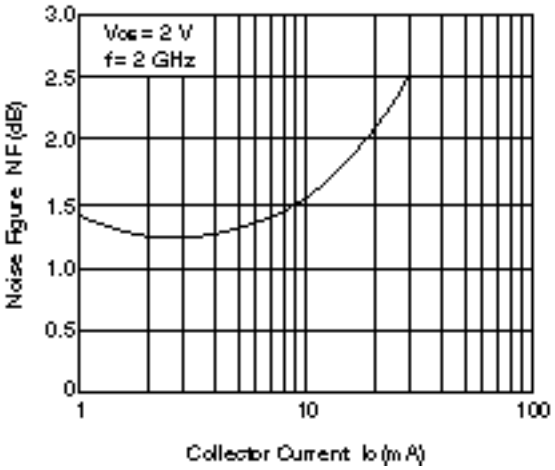


INSERTION POWER GAIN vs. COLLECTOR CURRENT



Remark The graphs indicate nominal characteristics.

NOISE FIGURE vs.
COLLECTOR CURRENT



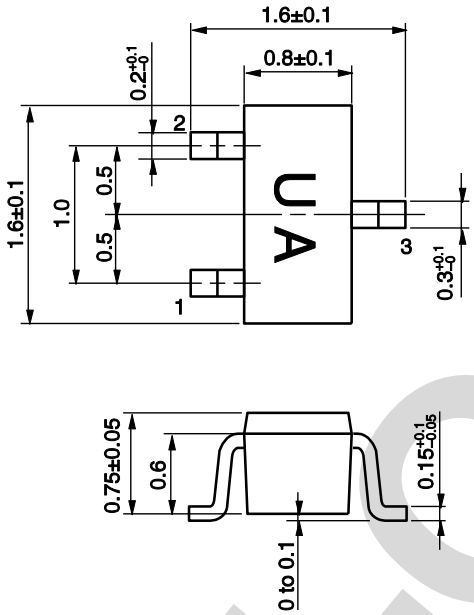
Remark The graph indicates nominal characteristics.

<R> **S-PARAMETERS**

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

3-PIN ULTRA SUPER MINIMOLD (19, 1608 PKG) (UNIT: mm)



PIN CONNECTIONS

1. Emitter
2. Base
3. Collector

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